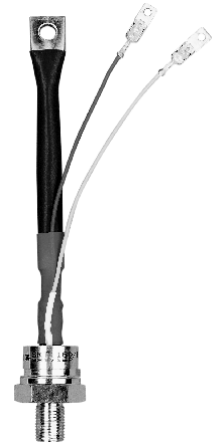


**Thyristors**

**SKT 130  
SKT 160**



**Features**

- Hermetic metal cases with ceramic insulators
- Threaded studs ISO M16 x 1,5 or UNF 3/4-16
- International standard cases

**Typical Applications**

- DC motor control (e. g. for machine tools)
- Controlled rectifiers (e. g. for battery charging)
- AC controllers (e. g. for temperature control)

| V <sub>RSM</sub> | V <sub>RRM</sub><br>V <sub>DRM</sub> | $\left(\frac{dv}{dt}\right)_{cr}$ | I <sub>TRMS</sub> (maximum values for continuous operation) |                      |
|------------------|--------------------------------------|-----------------------------------|---|----------------------|
|                  |                                      |                                   | 220 A   | 280 A                |
| V                | V                                    | V/μs                              | I <sub>TAV</sub> (sin. 180; T <sub>case</sub> = . . . °C)   |                      |
|                  |                                      |                                   | 140 A (80 °C)   | 178 A (78 °C)        |
| 500              | 400                                  | 500                               | <b>SKT 130/04 D</b>   | <b>SKT 160/04 D</b>  |
| 700              | 600                                  | 500                               | <b>SKT 130/06 D</b>   | <b>SKT 160/06 D</b>  |
| 900              | 800                                  | 500                               | <b>SKT 130/08 D</b>   | <b>SKT 160/08 D</b>  |
| 1300             | 1200                                 | 1000                              | <b>SKT 130/12 E</b>   | <b>SKT 160/12 E*</b> |
| 1500             | 1400                                 | 1000                              | <b>SKT 130/14 E</b>   | <b>SKT 160/14 E</b>  |
| 1700             | 1600                                 | 1000                              | <b>SKT 130/16 E</b>   | <b>SKT 160/16 E*</b> |

| Symbol                            | Conditions  | SKT 130            | SKT 160          | Units                                |
|-----------------------------------|---|--------------------|------------------|--------------------------------------|
| I <sub>TAV</sub>                  | sin. 180; T <sub>case</sub> = 85 °C   | 130                | 160              | A                                    |
| I <sub>TSM</sub>                  | T <sub>vj</sub> = 25 °C; 10 ms<br>T <sub>vj</sub> = 130 °C; 10 ms                   | 3500<br>3000       | 4300<br>3750     | A<br>A                               |
| i <sup>2</sup> t                  | T <sub>vj</sub> = 25 °C; 8,35 ... 10 ms<br>T <sub>vj</sub> = 130 °C; 8,35 ... 10 ms | 61 000<br>45 000   | 92 500<br>70 000 | A <sup>2</sup> s<br>A <sup>2</sup> s |
| t <sub>gd</sub>                   | T <sub>vj</sub> = 25 °C; I <sub>G</sub> = 1 A;<br>di <sub>G</sub> /dt = 1 A/μs      | typ. 1             |                  | μs                                   |
| t <sub>gr</sub>                   | V <sub>D</sub> = 0,67 · V <sub>DRM</sub>  | typ. 2             |                  | μs                                   |
| (di/dt) <sub>cr</sub>             | f = 50 . . . 60 Hz  | 100                |                  | A/μs                                 |
| I <sub>H</sub>                    | T <sub>vj</sub> = 25 °C   | typ. 150; max. 250 |                  | mA                                   |
| I <sub>L</sub>                    | T <sub>vj</sub> = 25 °C; R <sub>G</sub> = 33 Ω                                      | typ. 300; max. 600 |                  | mA                                   |
| t <sub>q</sub>                    | T <sub>vj</sub> = 130 °C; typ.  | 120                |                  | μs                                   |
| V <sub>T</sub>                    | T <sub>vj</sub> = 25 °C; I <sub>T</sub> = 500 A; max.                               | 2,25               | 1,75             | V                                    |
| V <sub>T(TO)</sub>                | T <sub>vj</sub> = 130 °C  | 1,20               | 1,0              | V                                    |
| r <sub>T</sub>                    | T <sub>vj</sub> = 130 °C  | 2,2                | 1,5              | mΩ                                   |
| I <sub>DD</sub> , I <sub>RD</sub> | T <sub>vj</sub> = 130 °C; V = V <sub>DRM</sub> ; V <sub>RRM</sub>                   | 50                 | 50               | mA                                   |
| V <sub>GT</sub>                   | T <sub>vj</sub> = 25 °C   | 3                  |                  | V                                    |
| I <sub>GT</sub>                   | T <sub>vj</sub> = 25 °C   | 200                |                  | mA                                   |
| V <sub>GD</sub>                   | T <sub>vj</sub> = 130 °C  | 0,25               |                  | V                                    |
| I <sub>GD</sub>                   | T <sub>vj</sub> = 130 °C  | 10                 |                  | mA                                   |
| R <sub>thjc</sub>                 | cont.   | 0,16               |                  | °C/W                                 |
|                                   | sin. 180/rec. 120   | 0,18/0,20          |                  | °C/W                                 |
| R <sub>thch</sub>                 |   | 0,03               |                  | °C/W                                 |
| T <sub>vj</sub>                   |   | - 40 ... +130      |                  | °C                                   |
| T <sub>stg</sub>                  |   | - 55 ... +150      |                  | °C                                   |
| M                                 | SI units  | 30                 |                  | Nm                                   |
|                                   | US units  | 265                |                  | lb. in.                              |
| a                                 |   | 5 · 9,81           |                  | m/s <sup>2</sup>                     |
| w                                 |   | 210                |                  | g                                    |
| Case                              |   | B 6                |                  |                                      |

\* Available with UNF thread 3/4-16 UNF2A; e.g. SKT 160/12 E UNF

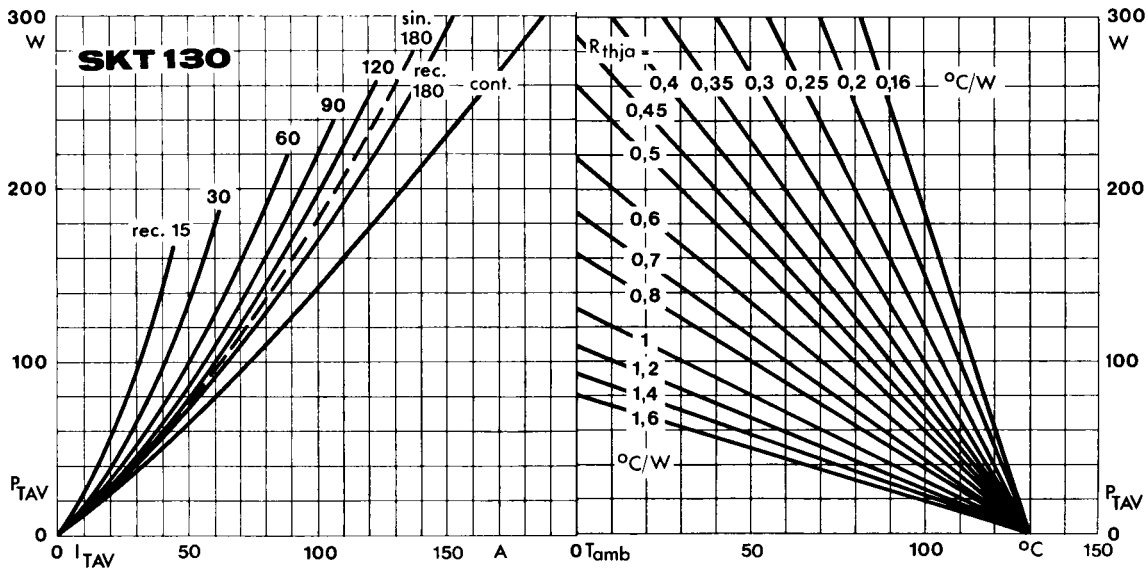


Fig. 1 a Power dissipation vs. on-state current and ambient temperature

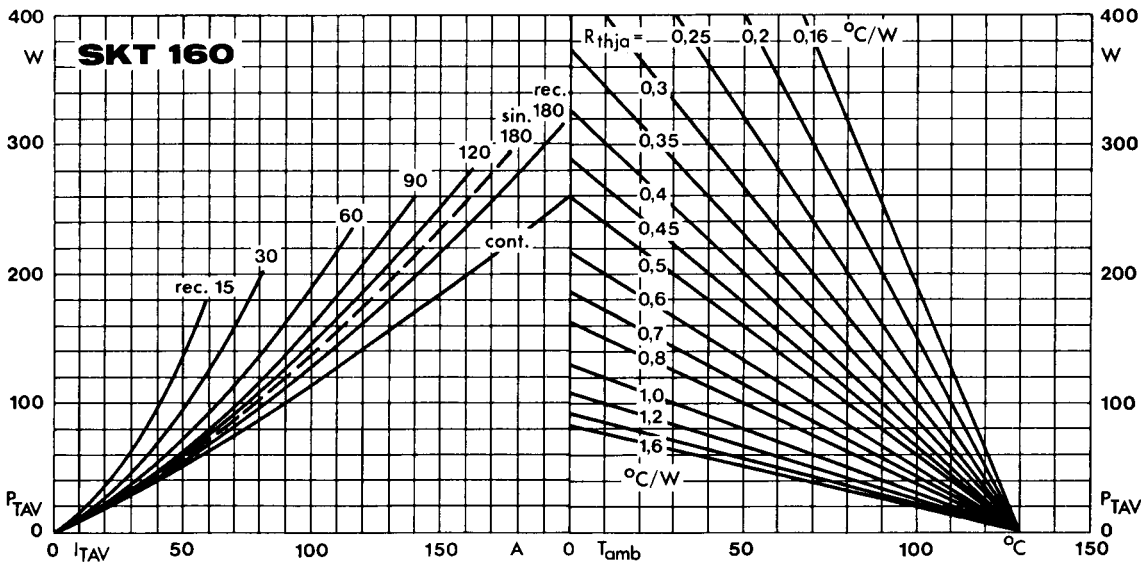


Fig. 1 b Power dissipation vs. on-state current and ambient temperature

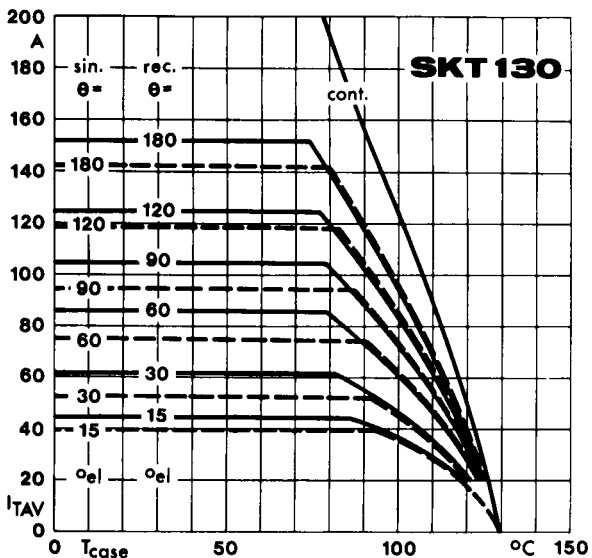


Fig. 2 a Rated on-state current vs. case temperature

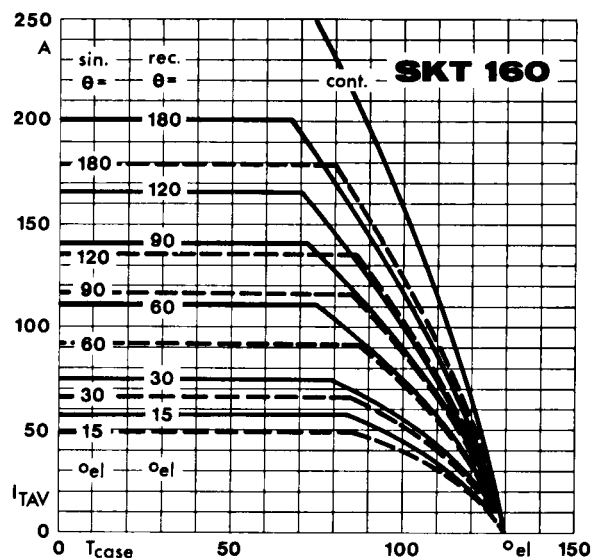


Fig. 2 b Rated on-state current vs. case temperature

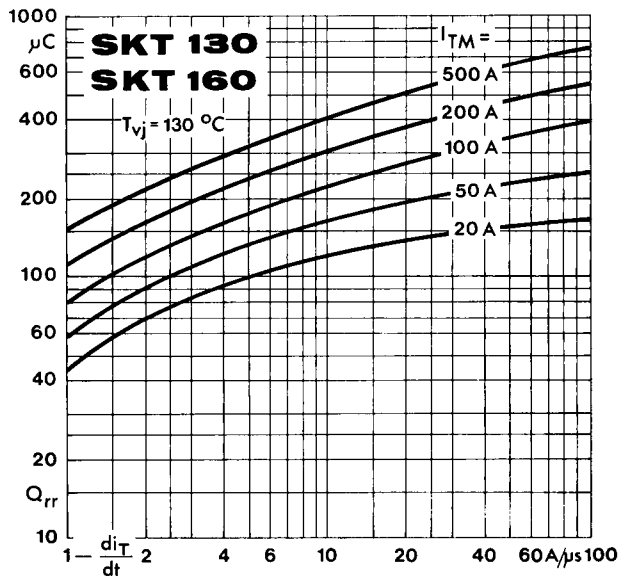


Fig. 3 Recovered charge vs. current decrease

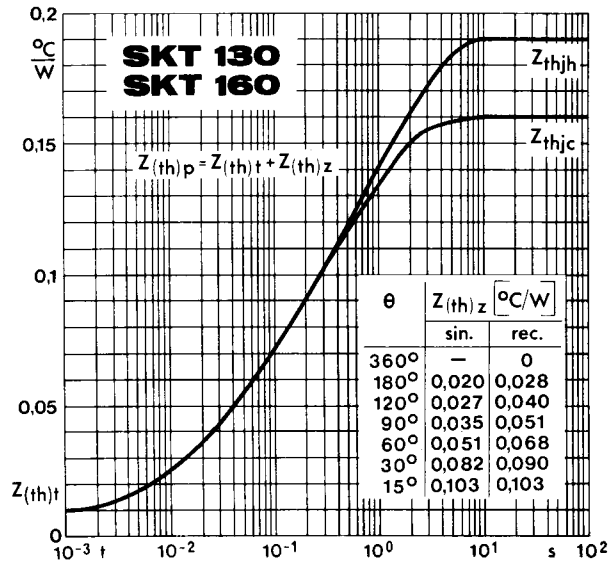


Fig. 4 Transient thermal impedance vs. time

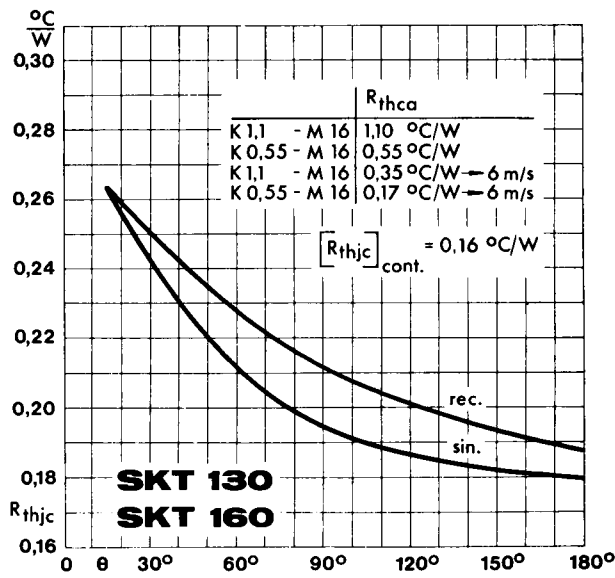


Fig. 5 Thermal resistance vs. conduction angle

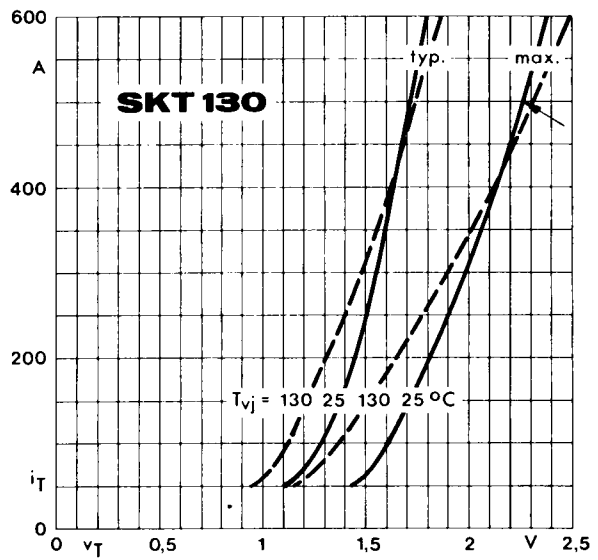


Fig. 6 a On-state characteristics

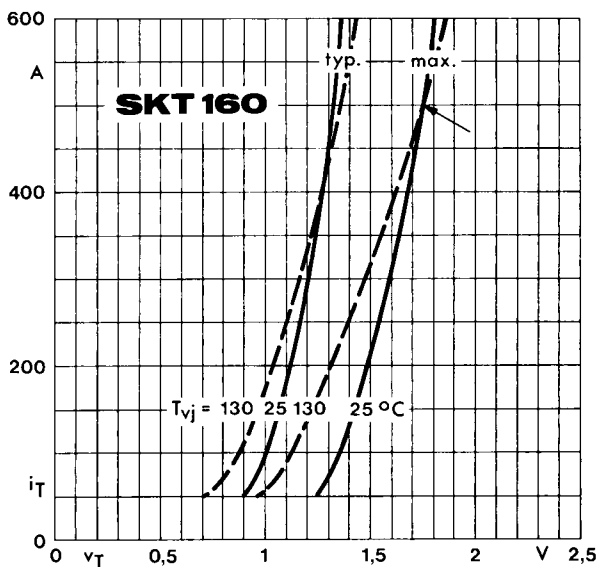


Fig. 6 b On-state characteristics

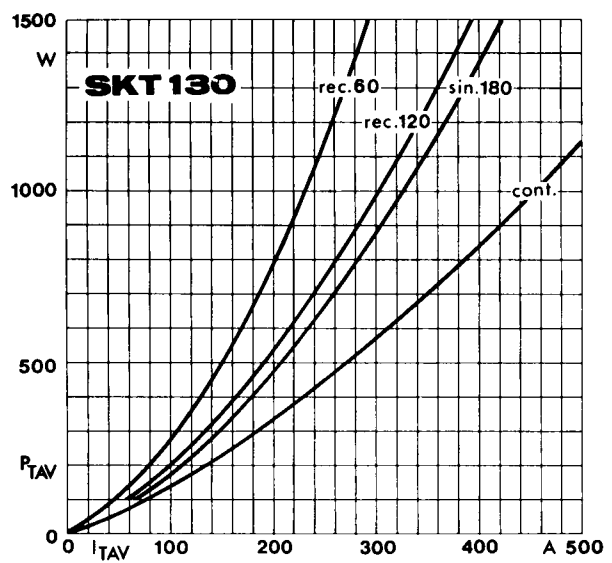


Fig. 7 a Power dissipation vs. on-state current

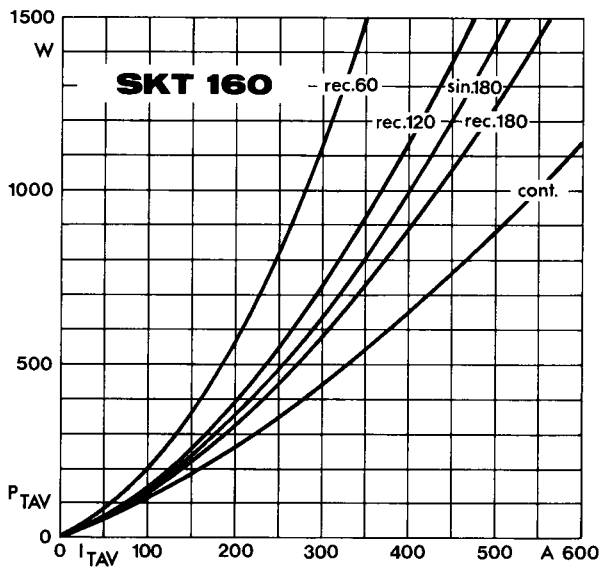


Fig. 7 b Power dissipation vs. on-state current

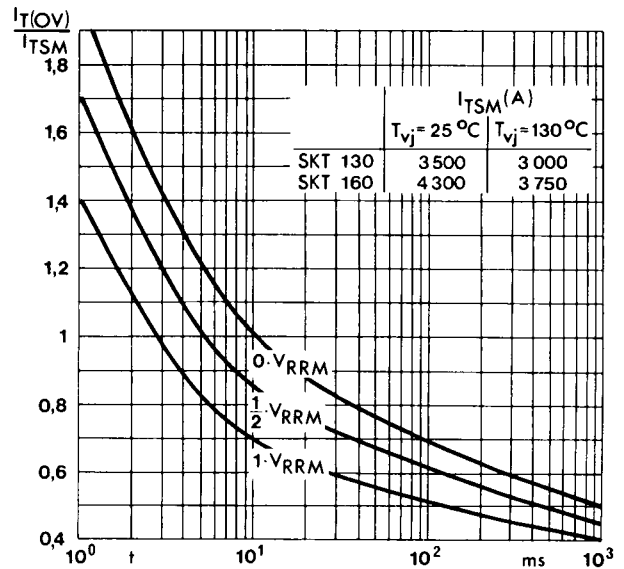


Fig. 8 Surge overload current vs. time

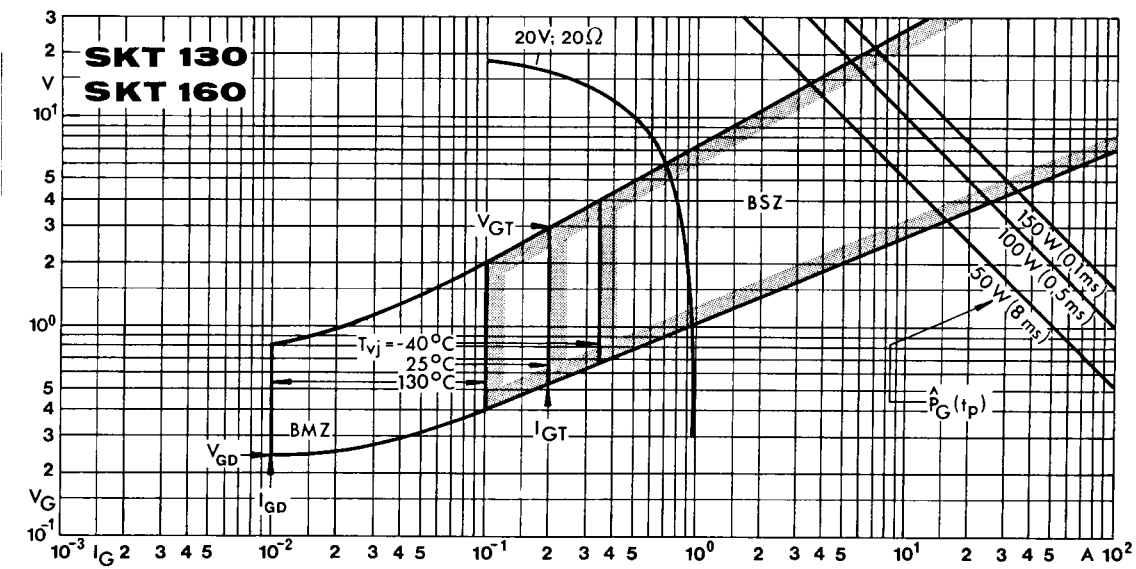


Fig. 9 Gate trigger characteristics

**SKT 55  
SKT 80  
SKT 100**

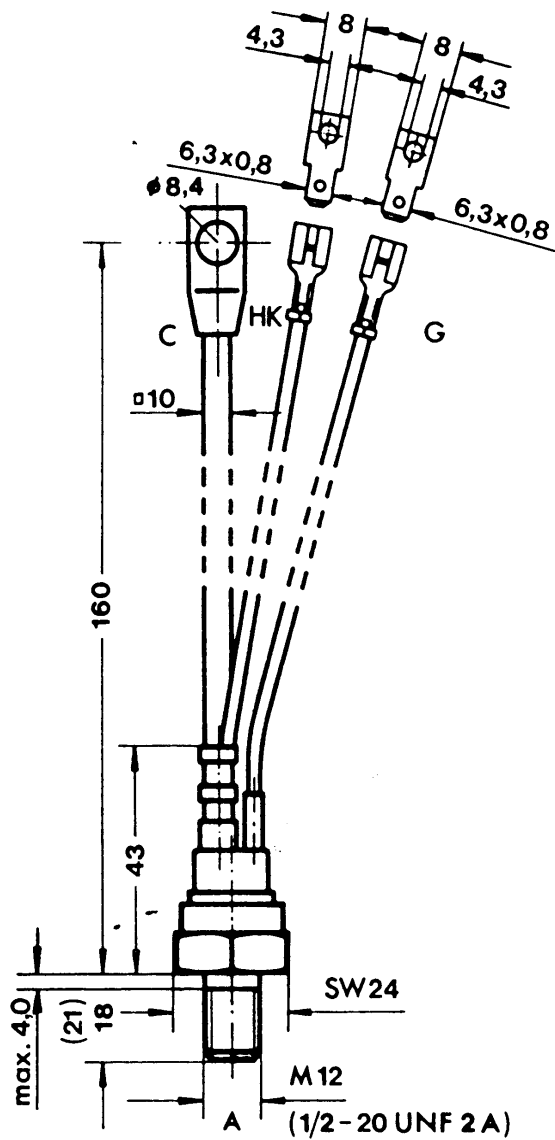
Case B 5

IEC-Publ. 191-2: (A 12 MA, A 12 U)

DIN 41892: (204 B 3)

BS 3934: SO – 30 C

JEDEC: TO – 209 (TO – 94)<sup>1)</sup>



<sup>1)</sup> modified version. In the USA and Canada these types are available with the original TO-209 (TO-94) dimensions. TO-208 AD (TO-83) with flag terminals is also available.

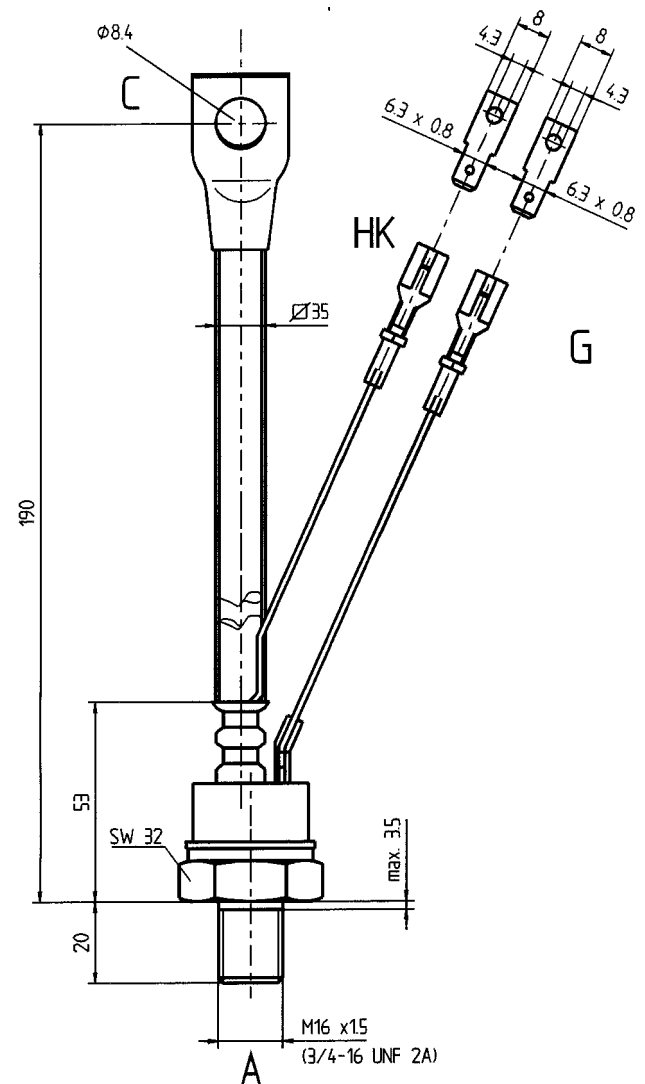
**SKT 130  
SKT 160**

Case B 6

IEC-Publ. 191-2: A 47 MC

DIN 41893: 205 B 4

JEDEC: TO-209 (TO-93)



Dimensions in mm

- C: Cathode terminal (red sleeve)
- A: Anode terminal
- G: Gate terminal (yellow sleeve)
- HK: Auxiliary cathode terminal (red sleeve)